

**WBFBP-03B Plastic-Encapsulate Transistors****TP9015NND03 TRANSISTOR****DESCRIPTION**

PNP Epitaxial Silicon Transistor

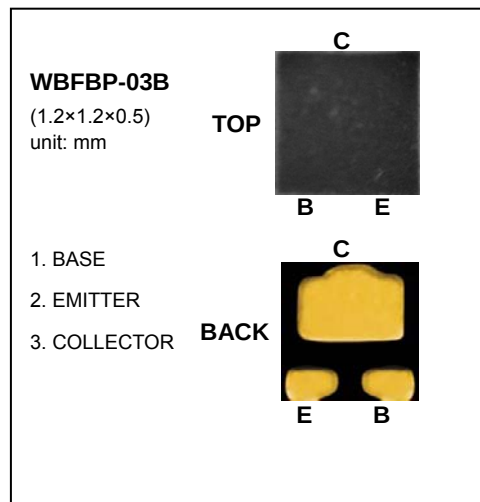
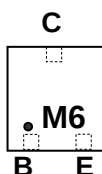
FEATURESHigh h_{FE} and good linearity

Complementary to TP9014NND03

APPLICATION

Low Frequency, Low Noise Amplifier

For portable equipment:(i.e. Mobile phone,MP3, MD,CD-ROM, DVD-ROM,Note book PC, etc.)

MARKING: M6**MAXIMUM RATINGS $T_A=25^{\circ}\text{C}$ unless otherwise noted**

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-50	V
V_{CEO}	Collector-Emitter Voltage	-45	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current -Continuous	-0.1	A
P_C	Collector Dissipation	0.15	W
T_J	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55-150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}$, $I_E = 0$	-50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -0.1\text{mA}$, $I_B = 0$	-45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -100\mu\text{A}$, $I_C = 0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB} = -50\text{V}$, $I_E = 0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{V}$, $I_C = 0$			-0.1	μA
DC current gain	h_{FE}	$V_{CE} = -5\text{V}$, $I_C = -1\text{mA}$	200		1000	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -100\text{mA}$, $I_B = -10\text{mA}$			-0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -100\text{mA}$, $I_B = -10\text{mA}$			-1	V
Transition frequency	f_T	$V_{CE} = -5\text{V}$, $I_C = -10\text{mA}$, $f = 30\text{MHz}$	150			MHz
Collector output capacitance	C_{obo}	$V_{CB} = -10\text{V}$, $I_E = 0$, $f = 1\text{MHz}$			7	pF
Noise figure	NF	$V_{CE} = -5\text{V}$, $I_C = -0.2\text{mA}$, $f = 1\text{KHz}$, $R_S = 2\text{K}\Omega$			6	dB

CLASSIFICATION OF h_{FE}

Rank	L	H
Range	200-450	450-1000

Typical Characteristics

TP9015NND03

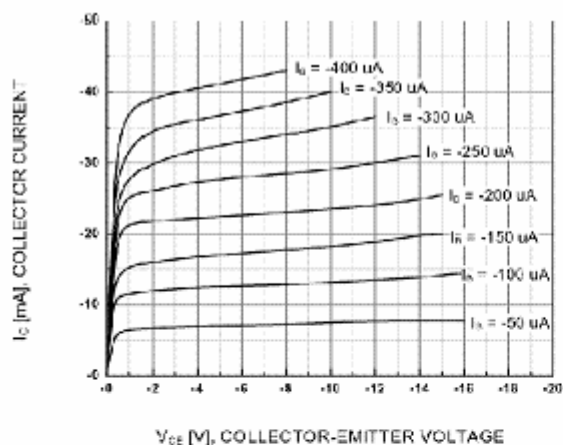


Figure 1. Static Characteristic

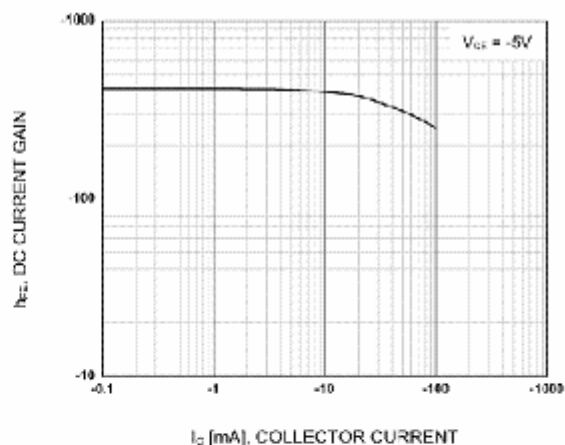


Figure 2. DC current Gain

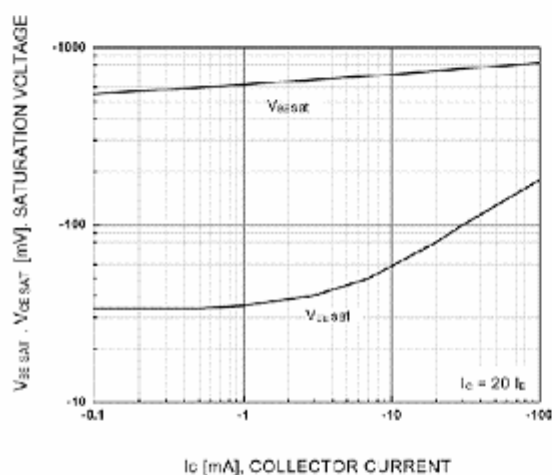


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

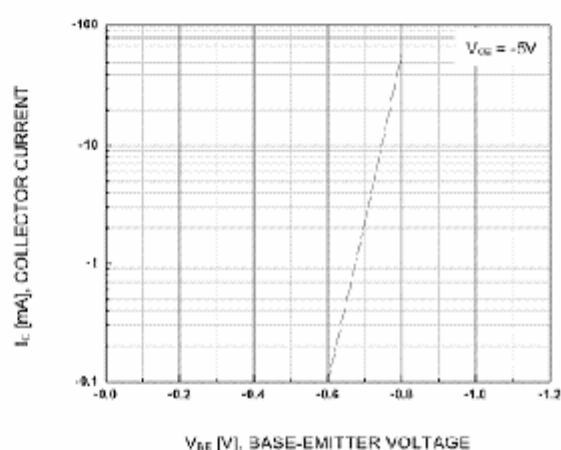


Figure 4. Base-Emitter On Voltage

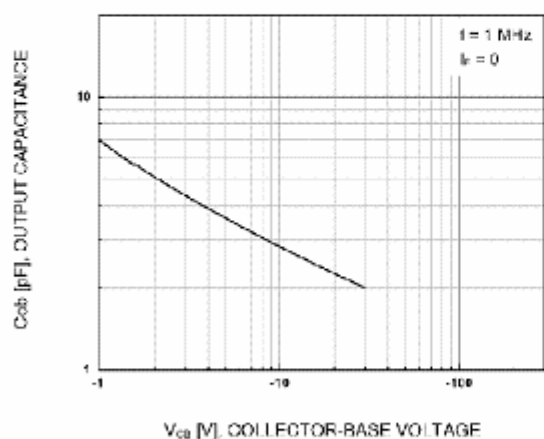


Figure 5. Collector Output Capacitance

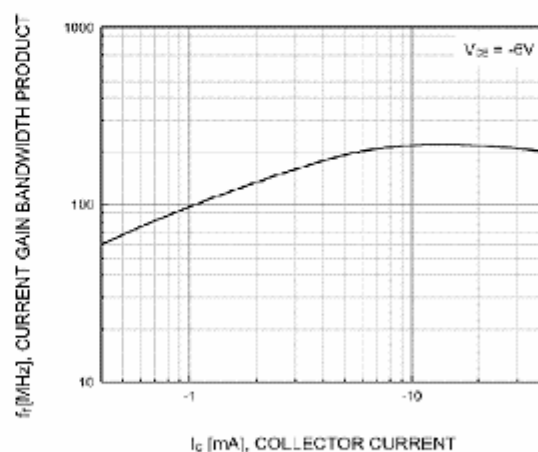


Figure 6. Current Gain Bandwidth Product